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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Dock t No. 040373/0300

Applicant: Toshiyuki HIROTA, et al.

Title: SEMICONDUCTOR DEVICE WITH HIGH- AND LOW-DENSITY
REGIONS OF TRANSISTOR ELEMENTS ON SINGLE
SEMICONDUCTOR SUBSTRATE, AND METHOD OF
MANUFACTURING SUCH SEMICONDUCTOR DEVICE

Serial No.: 09/741,195

Filed: December 21, 2000

Examiner: Vu, Quang D.

Art Unit: 2811

AMENDMENT AND REPLY UNDER 37 CFR 1.111

Mail Stop NON-FEE AMENDMENT
Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Sir:

This communication is responsive to the Non-Final Office Action dated August 6, 2003, concerning the above-referenced patent application.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this document.

Remarks/Arguments begin on page 12 of this document.

Please amend the application as follows:

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